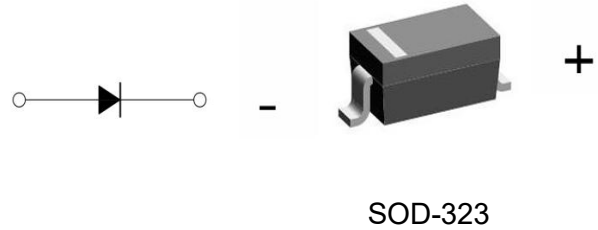


### Schottky Barrier Diode

Parameter	Value	Unit
$V_R$	30	V
$I_{F(AV)}$	500	mA



### Features

- Ultrafast Reverse Recovery Time
- Low Power Losses, High Efficiency
- Low Forward Voltage Drop
- High Surge Capability

### Applications

- Low Voltage
- High-Frequency Inverters
- Free Wheeling
- Switching circuit

### Absolute Maximum Ratings ( $T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Maximum repetitive peak reverse voltage	$V_{RRM}$	30	V
Maximum RMS voltage	$V_{RMS}$	20	V
Maximum DC blocking voltage	$V_{DC}$	20	V
Maximum average forward rectified current	$I_{F(AV)}$	500	mA
Non-repetitive Peak Forward Surge Current @ $t=8.3\text{ms}$ Half-sine wave	$I_{FSM}$	2.0	A
Power Dissipation	$P_D$	250	mW
Junction Temperature	$T_J$	125	$^\circ\text{C}$
Storage temperature range	$T_{STG}$	-65 ~ +150	$^\circ\text{C}$
Typical thermal resistance	$R_{\theta JA}$	400	$^\circ\text{C}/\text{W}$

### Electrical Characteristics ( $T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Test Conditions	Min	Type	Max	Unit
Maximum forward voltage	$V_F$	$I_F=0.1\text{A}$	-	-	0.36	V
		$I_F=0.5\text{A}$	-	-	0.47	
Maximum reverse current	$I_R$	$V_R=20\text{V}$	-	-	100	$\mu\text{A}$

**Typical Characteristics**

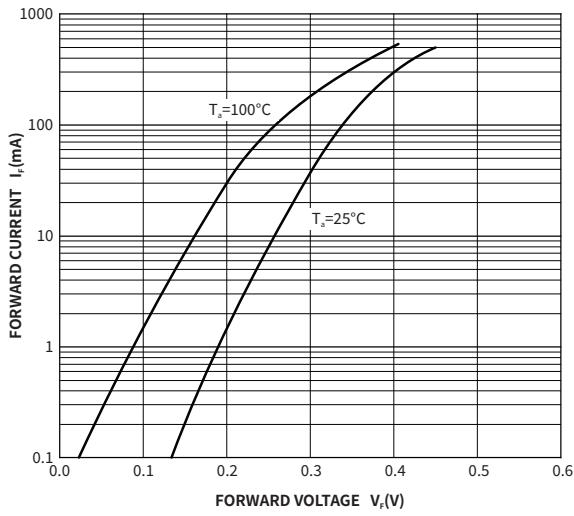


Fig.1 Typical Instantaneous Forward Characteristics

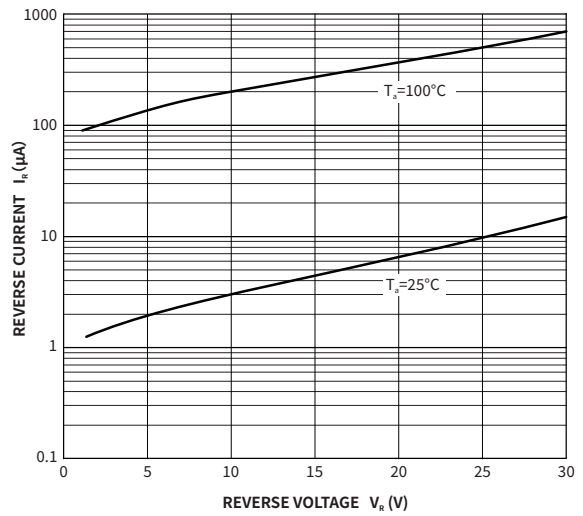


Fig.2 Typical Reverse Characteristics

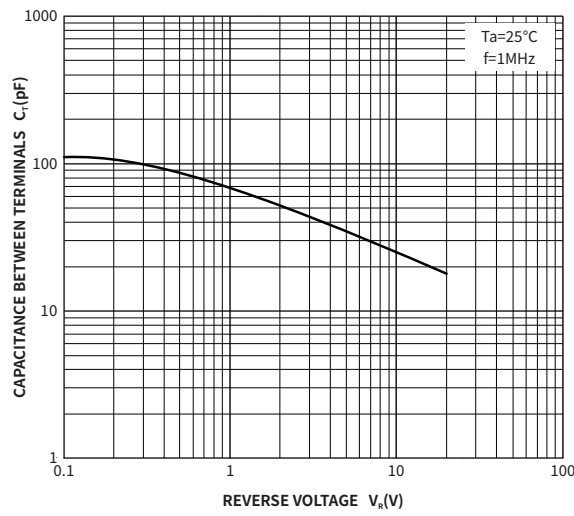


Fig.3 Typical Junction Capacitance

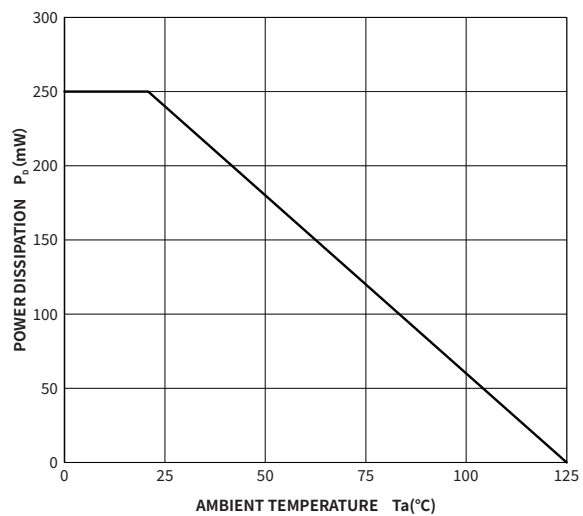
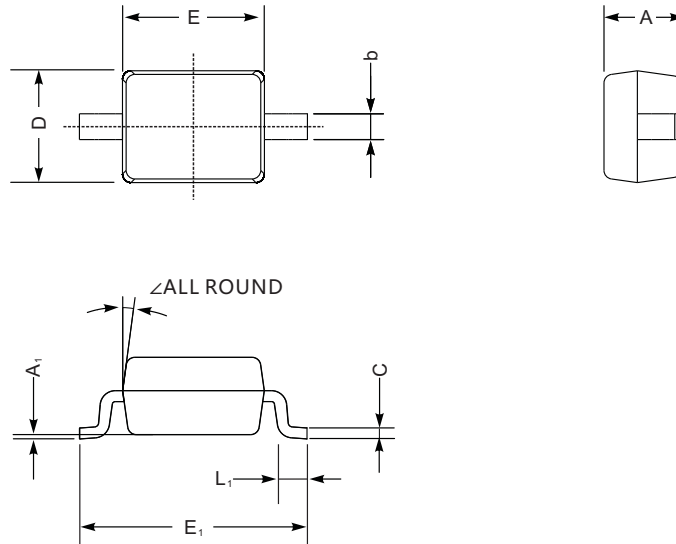


Fig.4 Power Derating Curve

**Package Outlines (Units: mm)**

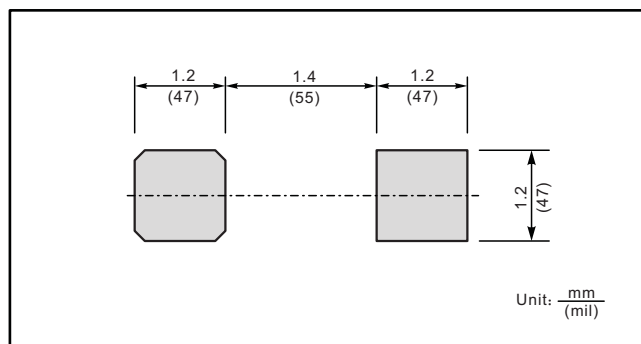
Plastic surface mounted package; 2 leads



SOD-323 mechanical data

UNIT		A	C	D	E	E <sub>1</sub>	b	L <sub>1</sub>	A <sub>1</sub>	∠
mm	max	1.1	0.15	1.4	1.8	2.75	0.4	0.45	0.2	9°
	min	0.8	0.08	1.2	1.4	2.55	0.25	0.2	—	
mil	max	43	5.9	55	70	108	16	16	8	
	min	32	3.1	47	63	100	9.8	7.9	—	

**The recommended mounting pad size**



**\*Important Usage Information and Disclaimer**

The specifications of Zhuhai Hypersemi Co., Ltd. products are not guarantees of product characteristics. They reflect typical performance expected in standard applications, which may vary with specific uses. Users must conduct prior testing for their applications and make necessary adjustments.

Users are responsible for the safety of applications utilizing our products and must implement adequate safety measures to prevent physical injury, fire, or other risks in case of product failure. It is the user's duty to ensure that application designs comply with all applicable laws and standards. Our products must not be used in any applications where a product failure could reasonably result in personal injury, unless specifically authorized in a signed document by Zhuhai Hypersemi Co., Ltd.

No representations or warranties are made regarding the accuracy or completeness of this information, including any claims of non-infringement of third-party intellectual property rights. Zhuhai Hypersemi Co., Ltd. assumes no liability for any applications or uses of its products and does not grant any licenses to its intellectual property rights or those of others. We also make no claims regarding non-infringement of third-party intellectual property rights that may arise from applications.

Due to technical requirements, our products may contain hazardous substances. For details, please contact your nearest sales office. This document replaces all previous information and may be updated. We reserve the right to make changes.